# MSKSEMI 美森科













**ESD** 

TSS

MOV

GDT

PIFD

L7808CV(MS)

Product specification





# Three-terminal positive voltage regulator

## **FEATURES**

Maximum Output current IOM: 1.5 A

Output voltage Vo: 8V

Continuous total dissipation

P<sub>D</sub>: 1.5 W (T<sub>a</sub> = 25 °C) 15 W(T<sub>c</sub> = 25 °C)

#### **Reference News**

| PACKAGE OUTLINE      | Marking     |
|----------------------|-------------|
| 1.II<br>2.G<br>3 3.C | OLINI MIO++ |

#### ABSOLUTE MAXIMUM RATINGS (Operating temperature range applies unless otherwise specified)

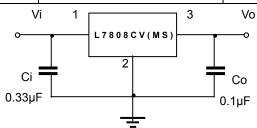
| Parameter                                   | Symbol           | Value    | Unit |
|---|------------------|----------|------|
| Input Voltage                               | Vi               | 35       | V    |
| Thermal Resistance from Junction to Ambient | R <sub>θJA</sub> | 83.3     | °C/W |
| Thermal Resistance from Junction to Case    | $R_{	heta JC}$   | 8.3      | °C/W |
| Operating Junction Temperature Range        | T <sub>OPR</sub> | 0~+150   | °C   |
| Storage Temperature Range                   | T <sub>STG</sub> | -55~+150 | °C   |

#### **ELECTRICAL CHARACTERISTICS AT SPECIFIED VIRTUAL JINCTION TEMPERATURE**

(Vi=14V,lo=500mA, Ci=0.33 $\mu F,$  Co=0.1 $\mu F,$  unless otherwise specified )

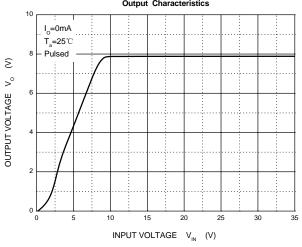
| Parameter                | Symbol                | Test conditions                                |             | Min | Тур  | Max | Unit |
|--------------------------|-----------------------|--|-------------|-----|------|-----|------|
|                          |                       |  | 25℃         | 7.7 | 8    | 8.3 | V    |
| Output Voltage           | Vo                    | 10.5V≤V <sub>i</sub> ≤23V, Io=5mA-1A,<br>P≤15W | 0-125℃      | 7.6 | 8    | 8.4 | V    |
| Load Regulation          | ΔVο                   | Io=5mA-1.5A                                    | <b>25</b> ℃ |     | 12   | 160 | mV   |
|                          |                       | lo=250mA-750mA                                 | <b>25</b> ℃ |     | 4    | 80  | mV   |
| Line Regulation          | ΔVο                   | 10.5V≤V i≤25V                                  | 25℃         |     | 6    | 160 | mV   |
|                          |                       | 11V≤V <sub>i</sub> ≤17V                        | 25℃         |     | 2    | 80  | mV   |
| Quiescent Current        | Iq                    |  | 25℃         |     | 4.3  | 8   | mA   |
| Quiescent Current Change | Δlq                   | 10.5V≤V <sub>i</sub> ≤25V                      | 0-125℃      |     |      | 1   | mA   |
|                          |                       | 5mA≤I <sub>O</sub> ≤1A                         | 0-125℃      |     |      | 0.5 | mA   |
| Output Voltage Drift     | $\Delta V_O/\Delta T$ | I <sub>O</sub> =5mA                            | 0-125℃      |     | -0.8 |     | mV/℃ |
| Output Noise Voltage     | V <sub>N</sub>        | 10Hz≤f≤100KHz                                  | 25℃         |     | 52   |     | μV   |
| Ripple Rejection         | RR                    | 11.5V≤V <sub>i</sub> ≤21.5V,f=120Hz            | 0-125℃      | 55  | 72   |     | dB   |
| Dropout Voltage          | Vd                    | Io=1A  | 25℃         |     | 2    |     | V    |
| Output Resistance        | Ro                    | f=1KH <sub>Z</sub>                             | 25℃         |     | 10   |     | mΩ   |
| Short Circuit Current    | Isc                   |  | 25℃         |     | 450  |     | mA   |
| Peak Current             | lpk                   |  | 25℃         |     | 2.0  |     | Α    |

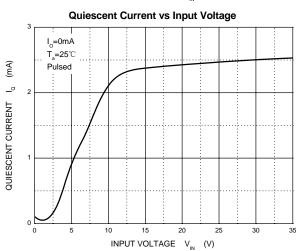


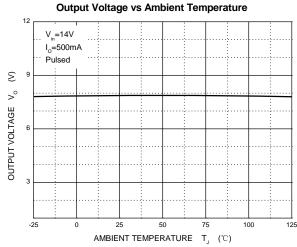


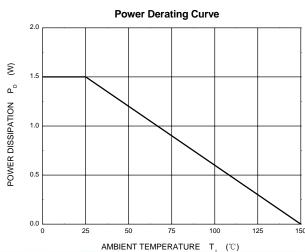


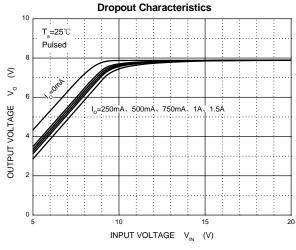
# **Typical Characterisitics**

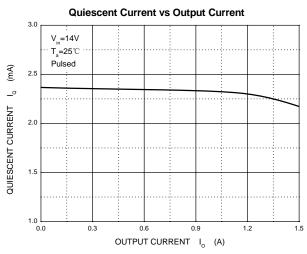


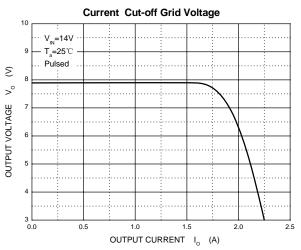






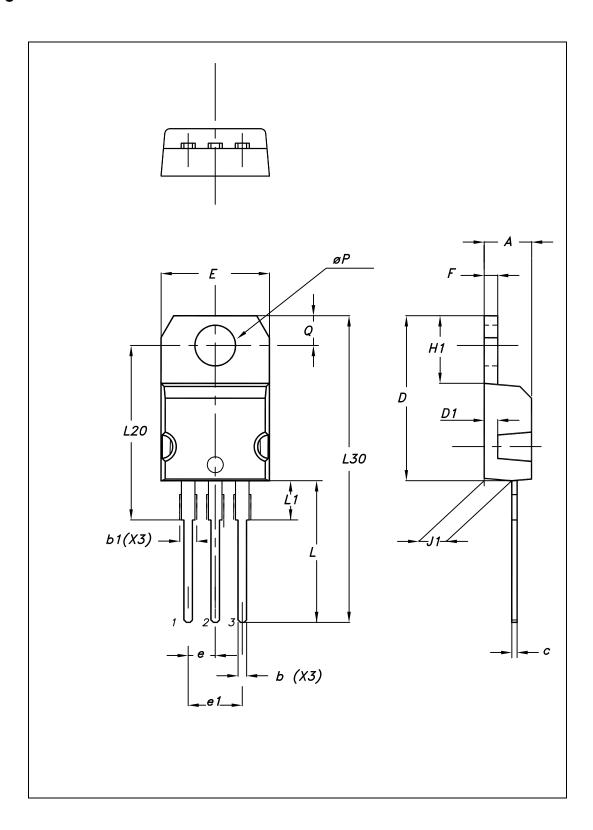








# Package mechanical data





# Package mechanical data

| Di   | mm    |       |       |  |  |
|------|-------|-------|-------|--|--|
| Dim. | Min.  | Тур.  | Max.  |  |  |
| Α    | 4.40  |       | 4.60  |  |  |
| b    | 0.61  |       | 0.88  |  |  |
| b1   | 1.14  |       | 1.70  |  |  |
| С    | 0.48  |       | 0.70  |  |  |
| D    | 15.25 |       | 15.75 |  |  |
| D1   |       | 1.27  |       |  |  |
| E    | 10    |       | 10.40 |  |  |
| е    | 2.40  |       | 2.70  |  |  |
| e1   | 4.95  |       | 5.15  |  |  |
| F    | 1.23  |       | 1.32  |  |  |
| H1   | 6.20  |       | 6.60  |  |  |
| J1   | 2.40  |       | 2.72  |  |  |
| L    | 13    |       | 14    |  |  |
| L1   | 3.50  |       | 3.93  |  |  |
| L20  |       | 16.40 |       |  |  |
| L30  |       | 28.90 |       |  |  |
| ØP   | 3.75  |       | 3.85  |  |  |
| Q    | 2.65  |       | 2.95  |  |  |

# **REEL SPECIFICATION**

| P/N         | PKG    | QTY                       |
|-------------|--------|---------------------------|
| L7808CV(MS) | TO-220 | 50/One tube 1000/a box of |



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